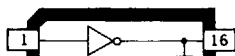


2001 THRU 2024

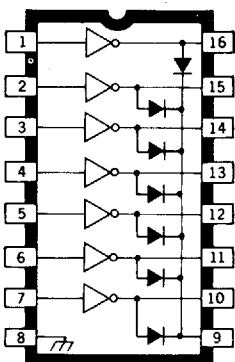
T-43-25

HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS

ULN20XXL



ULN20XXA



Dwg. No. A-9594

ABSOLUTE MAXIMUM RATINGS

Output Voltage, V_{CE}	
(ULN200X*, ULN2013A)	50 V
(ULN202X*)	95 V
Input Voltage, V_{IN}	30 V
Continuous Output Current, I_C	
(ULN200X*, ULN202X*)	500 mA
(ULN2013A)	600 mA
Continuous Input Current, I_{IN}	25 mA
Power Dissipation, P_D	
(one Darlington pair)	1.0 W
(total package)	See Graph
Operating Temperature Range,	
T_A	-20°C to +85°C
Storage Temperature Range,	
T_S	-55°C to +150°C

Note that the ULN2000A series (dual in-line package) and ULN2000L series (small-outline IC package) are electrically identical and share a common pin number assignment.

Ideally suited for interfacing between low-level logic circuitry and multiple peripheral power loads, the Series ULN2000A/L high-voltage, high-current Darlington arrays feature continuous load current ratings to 600 mA for each of the seven drivers. At an appropriate duty cycle depending on ambient temperature and number of drivers turned ON simultaneously, typical power loads totaling over 260 W (400 mA x 7, 95 V) can be controlled. Typical loads include relays, solenoids, stepping motors, magnetic print hammers, multiplexed LED and incandescent displays, and heaters. All devices feature open collector outputs with integral clamp diodes.

The ULN2001A device is a general-purpose array that may be used with external input current limiting, or with most PMOS or CMOS logic directly.

The Series ULN20x3A/L has series input resistors selected for operation directly with 5 V TTL or CMOS. These devices will handle numerous interface needs—particularly those beyond the capabilities of standard logic buffers.

The Series ULN20x4A/L features series input resistors for operation directly from 6 to 15 V CMOS or PMOS logic outputs.

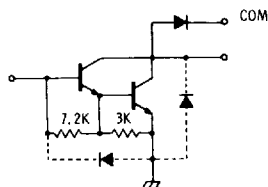
The Series ULN200xA/L is the standard Darlington array. The outputs are capable of sinking 500 mA and will withstand at least 50 V in the OFF state. Outputs may be paralleled for higher load current capability. The ULN2013A device is similar except that it will sink 600 mA. The Series ULN202xA/L will withstand 95 V in the OFF state.

These Darlington arrays are furnished in 16-pin dual in-line plastic packages (suffix A) and 16-lead surface-mountable SOICs (suffix L). All devices are pinned with outputs opposite inputs to facilitate ease of circuit board layout.

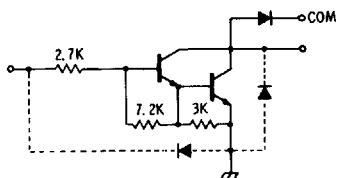
FEATURES

- TTL, DTL, PMOS, or CMOS Compatible Inputs
- Output Current to 600 mA
- Output Voltage to 95 V
- Transient-Protected Outputs
- Dual In-Line Plastic Package or Small-Outline IC Package

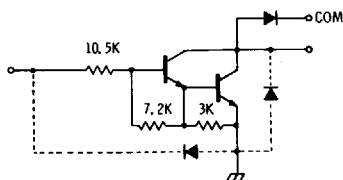
x = digit to identify specific device. Characteristic shown applies to family of devices with remaining digits as shown. See matrix on next page.

2001 THRU 2024**HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS****PARTIAL SCHEMATICS****ULN2001A (Each Driver)**

Dwg. No. A-9595

ULN20X3A/L (Each Driver)

Dwg. No. A-9651

ULN20X4A/L (Each Driver)

Dwg. No. A-9898A

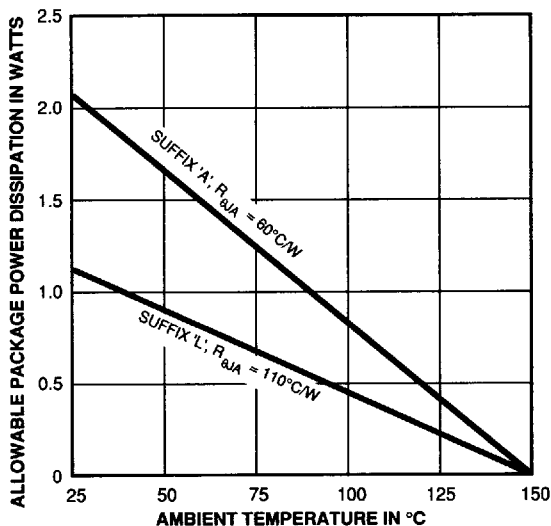
DEVICE NUMBER DESIGNATION

$V_{CE(MAX)}$	50V	50V	95V
$I_{C(MAX)}$	500 mA	600 mA	500 mA

Logic**Part Number**

General Purpose PMOS, CMOS	ULN2001A*	—	—
5 V TTL, CMOS	ULN2003A* ULN2003L*	ULN2013A*	ULN2023A* ULN2023L
6-15 V CMOS, PMOS	ULN2004A* ULN2004L*	—	ULN2024A

*Also available for operation between -40°C and $+85^{\circ}\text{C}$. To order, change prefix from 'ULN' to 'ULQ'.



Dwg. No. GP-006

X = Digit to identify specific device. Specification shown applies to family of devices with remaining digits as shown. See matrix above.

2001 THRU 2024

HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS

SERIES ULN2000A/L

ELECTRICAL CHARACTERISTICS at +25°C (unless otherwise noted).

Characteristic	Symbol	Test Fig.	Applicable Devices	Test Conditions	Limits			
					Min.	Typ.	Max.	Units
Output Leakage Current	I_{CEX}	1A	All	$V_{CE} = 50 \text{ V}, T_A = 25^\circ\text{C}$	—	< 1	50	μA
				$V_{CE} = 50 \text{ V}, T_A = 70^\circ\text{C}$	—	< 1	100	μA
		1B	ULN2004*	$V_{CE} = 50 \text{ V}, T_A = 70^\circ\text{C}, V_{IN} = 1.0 \text{ V}$	—	< 5	500	μA
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	2	All	$I_C = 100 \text{ mA}, I_B = 250 \mu\text{A}$	—	0.9	1.1	V
				$I_C = 200 \text{ mA}, I_B = 350 \mu\text{A}$	—	1.1	1.3	V
				$I_C = 350 \text{ mA}, I_B = 500 \mu\text{A}$	—	1.3	1.6	V
Input Current	$I_{IN(ON)}$	3	ULN2003*	$V_{IN} = 3.85 \text{ V}$	—	0.93	1.35	mA
			ULN2004*	$V_{IN} = 5.0 \text{ V}$	—	0.35	0.5	mA
				$V_{IN} = 12 \text{ V}$	—	1.0	1.45	mA
	$I_{IN(OFF)}$	4	All	$I_C = 500 \mu\text{A}, T_A = 70^\circ\text{C}$	50	65	—	μA
Input Voltage	$V_{IN(ON)}$	5	ULN2003*	$V_{CE} = 2.0 \text{ V}, I_C = 200 \text{ mA}$	—	—	2.4	V
				$V_{CE} = 2.0 \text{ V}, I_C = 250 \text{ mA}$	—	—	2.7	V
				$V_{CE} = 2.0 \text{ V}, I_C = 300 \text{ mA}$	—	—	3.0	V
		5	ULN2004*	$V_{CE} = 2.0 \text{ V}, I_C = 125 \text{ mA}$	—	—	5.0	V
				$V_{CE} = 2.0 \text{ V}, I_C = 200 \text{ mA}$	—	—	6.0	V
				$V_{CE} = 2.0 \text{ V}, I_C = 275 \text{ mA}$	—	—	7.0	V
				$V_{CE} = 2.0 \text{ V}, I_C = 350 \text{ mA}$	—	—	8.0	V
D-C Forward Current Transfer Ratio	h_{FE}	2	ULN2001A	$V_{CE} = 2.0 \text{ V}, I_C = 350 \text{ mA}$	1000	—	—	—
Input Capacitance	C_{IN}	—	All		—	15	25	pF
Turn-On Delay	t_{PLH}	8	All	$0.5 E_{IN}$ to $0.5 E_{OUT}$	—	0.25	1.0	μs
Turn-Off Delay	t_{PHL}	8	All	$0.5 E_{IN}$ to $0.5 E_{OUT}$	—	0.25	1.0	μs
Clamp Diode Leakage Current	I_R	6	All	$V_R = 50 \text{ V}, T_A = 25^\circ\text{C}$	—	—	50	μA
				$V_R = 50 \text{ V}, T_A = 70^\circ\text{C}$	—	—	100	μA
Clamp Diode Forward Voltage	V_F	7	All	$I_F = 350 \text{ mA}$	—	1.7	2.0	V

*Complete part number includes suffix to identify package style: A = DIP, L = SOIC.

2001 THRU 2024

HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS

TYPE ULN2013A

ELECTRICAL CHARACTERISTICS at +25°C (unless otherwise noted).

Characteristic	Symbol	Test Fig.	Test Conditions	Limits			
				Min.	Typ.	Max.	Units
Output Leakage Current	I_{CEX}	1A	$V_{CE} = 50 \text{ V}, T_A = 25^\circ\text{C}$	—	< 1	50	μA
			$V_{CE} = 50 \text{ V}, T_A = 70^\circ\text{C}$	—	< 1	100	μA
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	2	$I_C = 200 \text{ mA}, I_B = 350 \mu\text{A}$	—	1.1	1.3	V
			$I_C = 350 \text{ mA}, I_B = 500 \mu\text{A}$	—	1.3	1.6	V
			$I_C = 500 \text{ mA}, I_B = 600 \mu\text{A}$	—	1.7	1.9	V
Input Current	$I_{IN(ON)}$	3	$V_{IN} = 3.85 \text{ V}$	—	0.93	1.35	mA
	$I_{IN(OFF)}$	4	$I_C = 500 \mu\text{A}, T_A = 70^\circ\text{C}$	50	65	—	μA
Input Voltage	$V_{IN(ON)}$	5	$V_{CE} = 2.0 \text{ V}, I_C = 250 \text{ mA}$	—	—	2.7	V
			$V_{CE} = 2.0 \text{ V}, I_C = 300 \text{ mA}$	—	—	3.0	V
			$V_{CE} = 2.0 \text{ V}, I_C = 500 \text{ mA}$	—	—	3.5	V
Input Capacitance	C_{IN}	—		—	15	25	pF
Turn-On Delay	t_{ON}	8	$0.5 E_{IN}$ to $0.5 E_{OUT}$	—	0.25	1.0	μs
Turn-Off Delay	t_{OFF}	8	$0.5 E_{IN}$ to $0.5 E_{OUT}$	—	0.25	1.0	μs
Clamp Diode Leakage Current	I_R	6	$V_R = 50 \text{ V}, T_A = 25^\circ\text{C}$	—	—	50	μA
			$V_R = 50 \text{ V}, T_A = 70^\circ\text{C}$	—	—	100	μA
Clamp Diode Forward Voltage	V_F	7	$I_F = 350 \text{ mA}$	—	1.7	2.0	V
			$I_F = 500 \text{ mA}$	—	2.1	2.5	V

2001 THRU 2024**HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS****SERIES ULN2020A/L****ELECTRICAL CHARACTERISTICS at +25°C (unless otherwise noted).**

Characteristic	Symbol	Test Fig.	Applicable Devices	Test Conditions	Limits			
					Min.	Typ.	Max.	Units
Output Leakage Current	I_{CEX}	1A	All	$V_{CE} = 95\text{ V}, T_A = 25^\circ\text{C}$	—	< 1	50	μA
				$V_{CE} = 95\text{ V}, T_A = 70^\circ\text{C}$	—	< 1	100	μA
		1B	ULN2024A	$V_{CE} = 95\text{ V}, T_A = 70^\circ\text{C}, V_{IN} = 1.0\text{ V}$	—	< 5	500	μA
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	2	All	$I_C = 100\text{ mA}, I_B = 250\text{ }\mu\text{A}$	—	0.9	1.1	V
				$I_C = 200\text{ mA}, I_B = 350\text{ }\mu\text{A}$	—	1.1	1.3	V
				$I_C = 350\text{ mA}, I_B = 500\text{ }\mu\text{A}$	—	1.3	1.6	V
Input Current	$I_{IN(ON)}$	3	ULN2023*	$V_{IN} = 3.85\text{ V}$	—	0.93	1.35	mA
			ULN2024A	$V_{IN} = 5.0\text{ V}$	—	0.35	0.5	mA
				$V_{IN} = 12\text{ V}$	—	1.0	1.45	mA
	$I_{IN(OFF)}$	4	All	$I_C = 500\text{ }\mu\text{A}, T_A = 70^\circ\text{C}$	50	65	—	μA
Input Voltage	$V_{IN(ON)}$	5	ULN2023*	$V_{CE} = 2.0\text{ V}, I_C = 200\text{ mA}$	—	—	2.4	V
				$V_{CE} = 2.0\text{ V}, I_C = 250\text{ mA}$	—	—	2.7	V
				$V_{CE} = 2.0\text{ V}, I_C = 300\text{ mA}$	—	—	3.0	V
		5	ULN2024A	$V_{CE} = 2.0\text{ V}, I_C = 125\text{ mA}$	—	—	5.0	V
				$V_{CE} = 2.0\text{ V}, I_C = 200\text{ mA}$	—	—	6.0	V
				$V_{CE} = 2.0\text{ V}, I_C = 275\text{ mA}$	—	—	7.0	V
				$V_{CE} = 2.0\text{ V}, I_C = 350\text{ mA}$	—	—	8.0	V
Input Capacitance	C_{IN}	—	All		—	15	25	pF
Turn-On Delay	t_{PLH}	8	All	$0.5 E_{IN}$ to $0.5 E_{OUT}$	—	0.25	1.0	μs
Turn-Off Delay	t_{PHL}	8	All	$0.5 E_{IN}$ to $0.5 E_{OUT}$	—	0.25	1.0	μs
Clamp Diode Leakage Current	I_R	6	All	$V_R = 95\text{ V}, T_A = 25^\circ\text{C}$	—	—	50	μA
				$V_R = 95\text{ V}, T_A = 70^\circ\text{C}$	—	—	100	μA
Clamp Diode Forward Voltage	V_F	7	All	$I_F = 350\text{ mA}$	—	1.7	2.0	V

*Complete part number includes suffix to identify package style: A = DIP, L = SOIC.

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HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS

TEST FIGURES

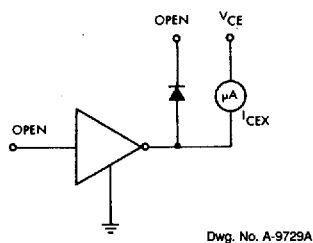


FIGURE 1A

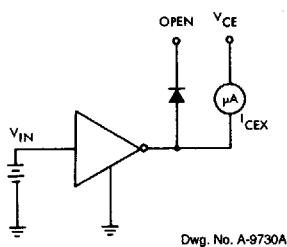


FIGURE 1B

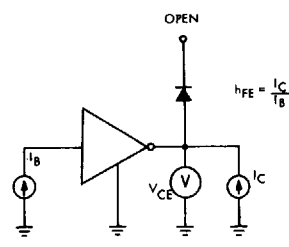


FIGURE 2

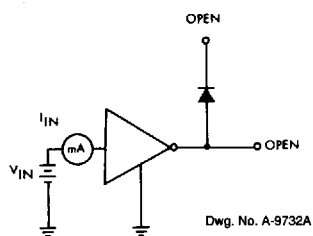


FIGURE 3

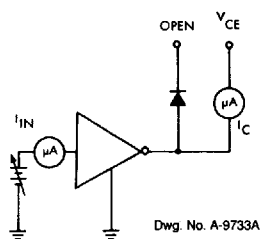


FIGURE 4

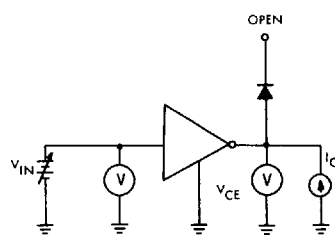


FIGURE 5

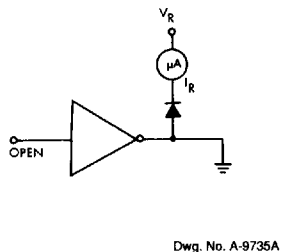


FIGURE 6

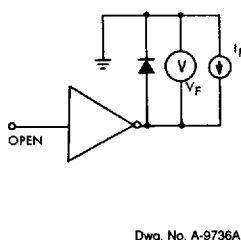


FIGURE 7

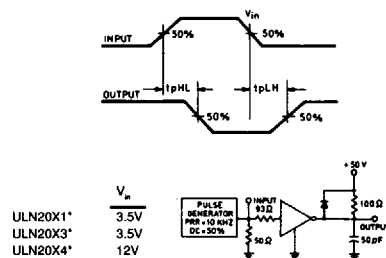


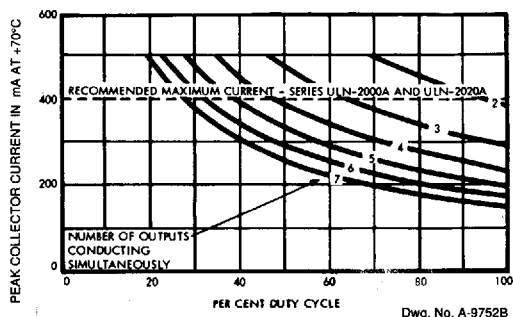
FIGURE 8

X = Digit to identify specific device. Specification shown applies to family of devices with remaining digits as shown.

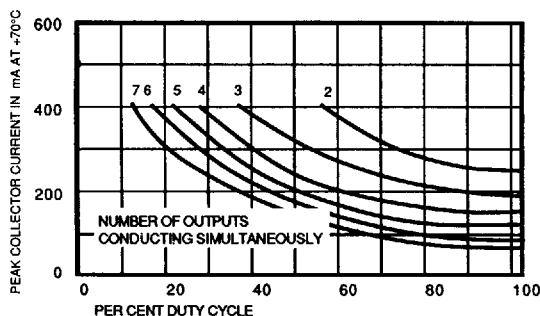
2001 THRU 2024

HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS

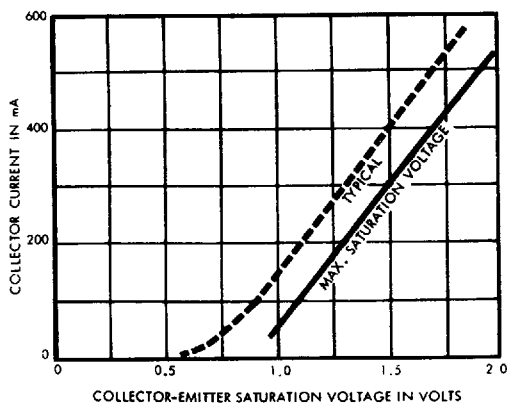
PEAK COLLECTOR CURRENT AS A FUNCTION OF DUTY CYCLE (DUAL IN-LINE PACKAGED DEVICES)



(SMALL OUTLINE PACKAGED DEVICES)

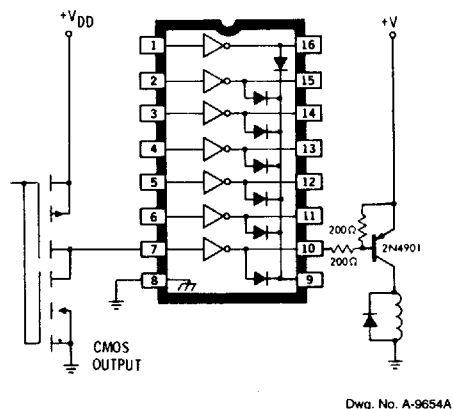
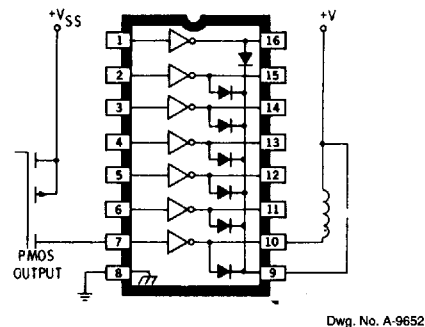


COLLECTOR CURRENT AS A FUNCTION OF SATURATION VOLTAGE

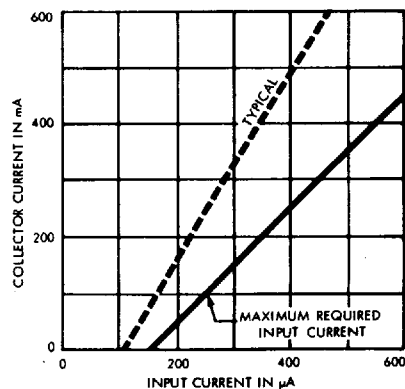


Dwg. No. A-9754C

TYPICAL APPLICATIONS



COLLECTOR CURRENT AS A FUNCTION OF INPUT CURRENT

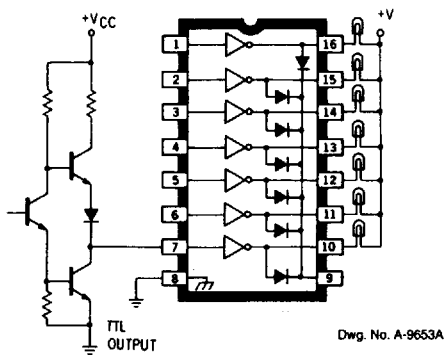


Dwg. No. A-10,872B

2001 THRU 2024

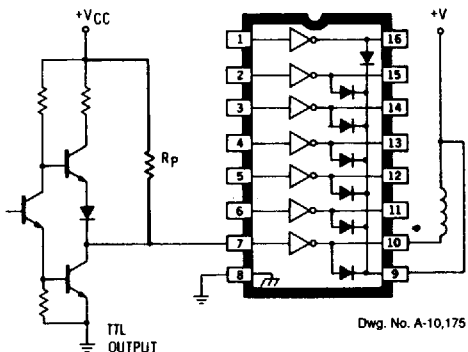
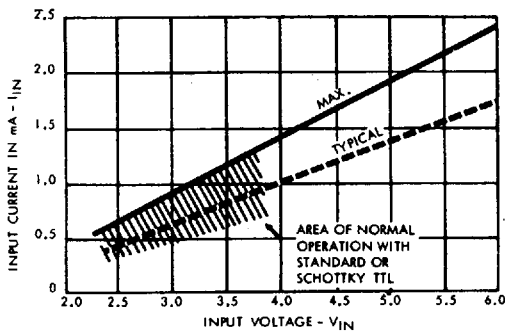
HIGH-VOLTAGE, HIGH-CURRENT DARLINGTON ARRAYS

TYPICAL APPLICATIONS



INPUT CURRENT AS A FUNCTION OF INPUT VOLTAGE

SERIES ULN20X3A/L



SERIES ULN20X4A/L

